

V210B/V210AB

HIGH VOLTAGE, PHOTO MOS RELAY

COSMO

FEATURES

- Normally Open, Single Pole Single Throw
- Control 350VAC or DC Voltage
- Switch 130mA Loads
- LED control Current, 5mA
- Low ON-Resistance
- $dv/dt, >500V/ms$
- Isolation Test Voltage, 3750VACrms

Absolute Maximum Ratings($T_a=25^{\circ}C$)

Emitter(Input)

Reverse Voltage	5.0V
Continuous Forward Current	50mA
Peak Forward Current	1A
Power Dissipation	100mW
Derate Linearly from $25^{\circ}C$	1.3mW/ $^{\circ}C$

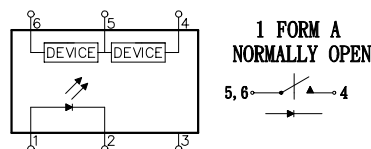
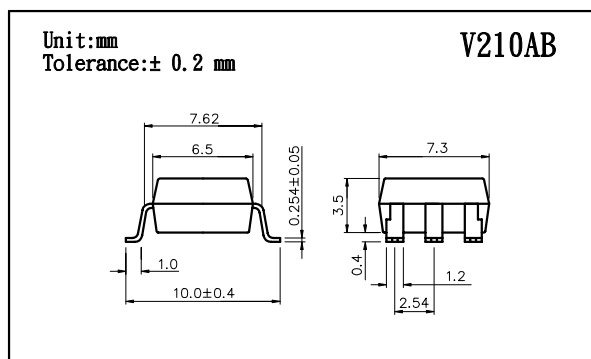
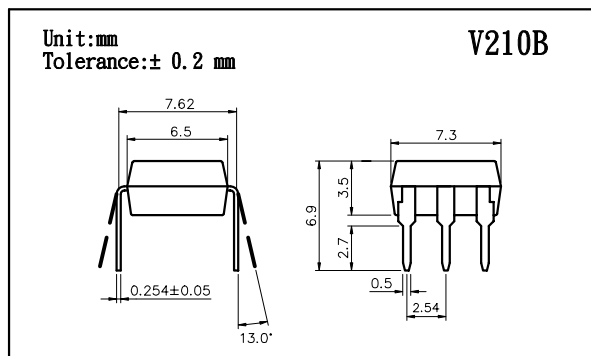
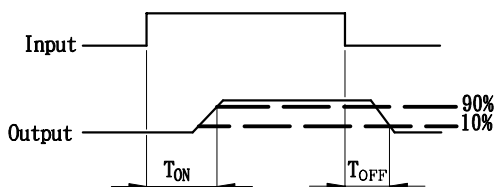
Detector(Output)

Output Breakdown Voltage	$\pm 350V$
Continuous Load Current	$\pm 130mA$
Power Dissipation	500mW

General Characteristics

Isolation Test Voltage	3750VACrms
Isolation Resistance $V_{io}=500V, T_a=25^{\circ}C$	$\geq 10^{10} \Omega$
Total Power Dissipation	550mW
Derate Linearly from $25^{\circ}C$	2.5mW/ $^{\circ}C$
Storage Temperature Range	$-40^{\circ}C$ to $+125^{\circ}C$
Operating Temperature Range	$-30^{\circ}C$ to $+85^{\circ}C$
Junction Temperature	$100^{\circ}C$
Soldering Temperature, 2mm from case, 10 sec	$260^{\circ}C$

- Turn on/Turn off time



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Characterisitcs

(Ta=25°C)

Description		Symbol	Min.	Typ.	Max.	Unit	Test Condition
Emitter(Input)							
Forward Voltage		VF		1.2	1.5	V	IF=10mA
Operation Input Current		IFON			5	mA	VL=± 20V, IL=100mA t=10mS
Recovery Input Current		IFOFF	0.05			mA	VL=± 20V, IL<=5uA
Detector (output)							
Output Breakdown Voltage		VB	350			V	IB=50uA
Output Off-State Leakage		IT(OFF)		0.2	2	uA	VT=100V, IF=0mA
I/O Capacitance		CISO		6		pF	IF=0, f=1MHz
ON Resistance	Con- nection	A		28	35	Ω	IL=100mA, IF=10mA
		B	RON	14	18		
		C		7	9		
Turn-on Time		TON		0.1	0.5	ms	IF=10mA, VL=± 20V
Turn-off Time		TOFF		0.3	0.5	ms	t=10ms, IL=± 100mA

Mos Relay Schematic and Wiring Diagrams

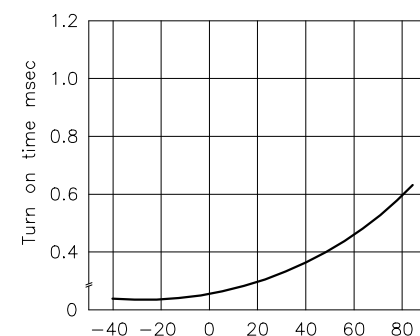
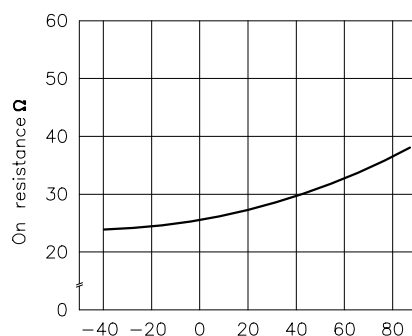
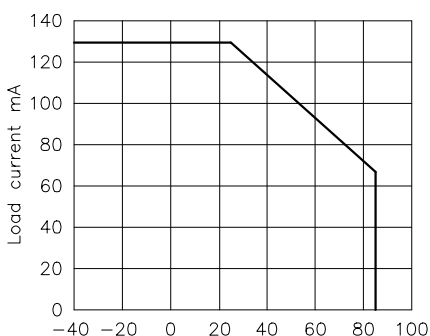
Type	Schematic	Output configuration	Load	Con- nection	Wiring Diagrams
V210B & V210AB		1a	AC/DC	A	
			DC	B	
			DC	C	

DATA CURVE

Load current vs. ambient temperature
Allowable ambient temperature:
-40°C to +80°C

On resistance vs. ambient temperature
Across terminals 4 and 6 pin
LED current: 5mA
Continuous load current: 130mA(DC)

Trun on time vs. ambient temperature
Load voltage 350V(DC)
LED current: 5mA
Continuous load current: 130mA(DC)

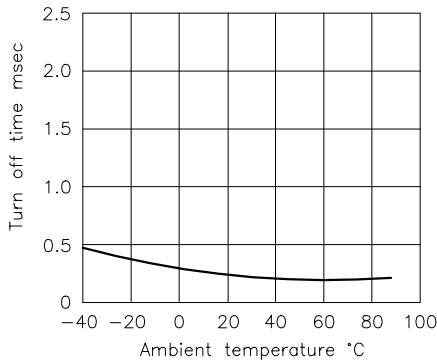


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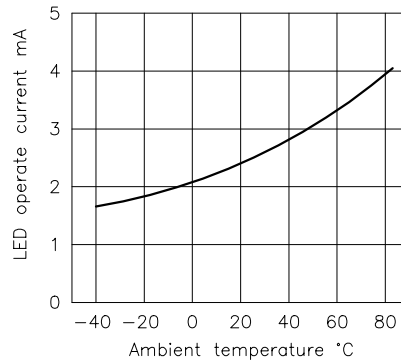
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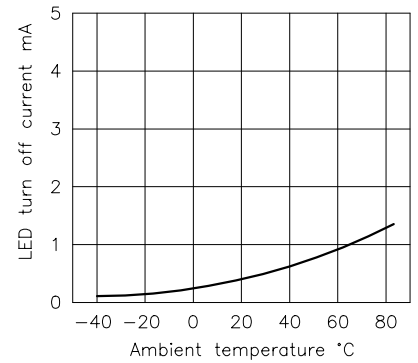
Turn off time vs. ambient temperature
LED current: 5mA; Load voltage: 350V(DC)
Continuous load current: 130mA(DC)



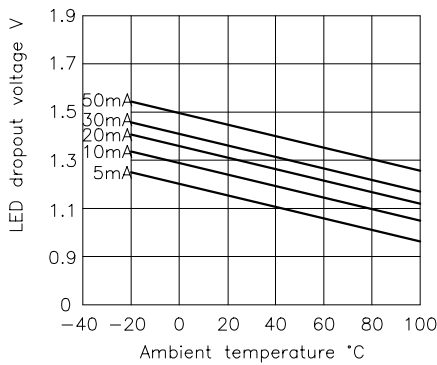
LED operate vs. ambient temperature
Load voltage: 350V(DC)
Continuous load current: 130mA(DC)



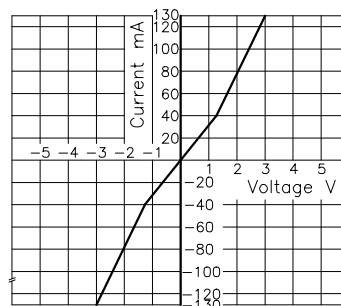
LED turn off current vs. ambient temperature
Load voltage: 350V(DC)
Continuous load current: 130mA(DC)



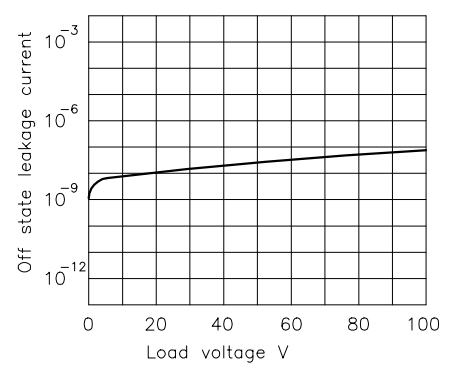
LED dropout voltage vs. ambient temperature
LED current: 5 to 50mA



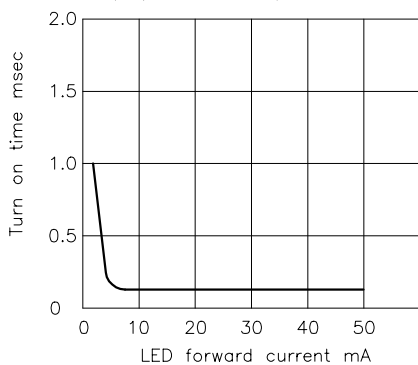
Voltage vs. current characteristics of output at MOS FET portion
Measured portion: across terminals 4 and 6 pin
Ambient temperature: 25°C



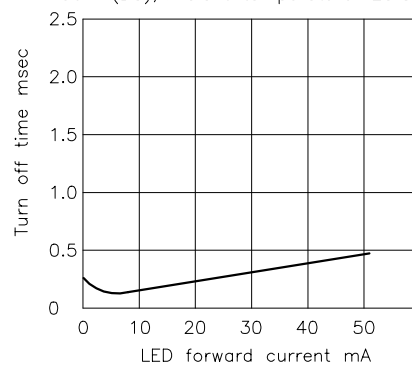
Off state leakage current
Across terminals 4 and 6 pin
Ambient temperature: 25°C



LED forward current vs. turn on time
Across terminals 4 and 6 pin; Load voltage: 350V(DC); Continuous load current: 130mA(DC); Ambient temperature: 25°C



LED forward current vs. turn off time
Across terminals 4 and 6 pin; Load voltage: 350V(DC); Continuous load current: 130mA(DC); Ambient temperature: 25°C



Applied voltage vs. output capacitance
Across terminals 4 and 6 pin
Frequency: 1MHz; Ambient temperature: 25°C

